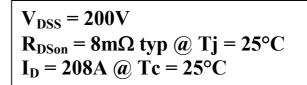
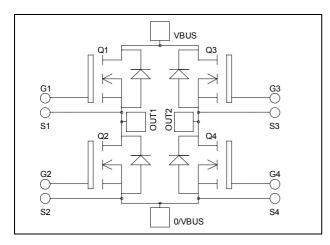


Full - Bridge MOSFET Power Module





Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS 7[®] FREDFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

G1 VBUS	OUTI O/VBUS G2
S1	\$2
53	
G3	OUI2 G4

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		200	V
Ţ	Continuous Drain Current	$T_c = 25$ °C	208	
I_D	Continuous Diam Current	$T_c = 80$ °C	155	A
I_{DM}	Pulsed Drain current		832	
V_{GS}	Gate - Source Voltage		±30	V
R_{DSon}	Drain - Source ON Resistance		10	mΩ
P_{D}	Maximum Power Dissipation $T_c = 25$ °C		781	W
I_{AR}	Avalanche current (repetitive and non repetitive)		100	A
E_{AR}	Repetitive Avalanche Energy		50	mJ
E_{AS}	Single Pulse Avalanche Energy		3000	1113

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 200V$ $T_j = 25^{\circ}C$			375	μΑ
		$V_{GS} = 0V, V_{DS} = 160V$ $T_j = 125^{\circ}C$			1500	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 104A$		8	10	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 5mA$			5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±150	nA

Dynamic Characteristics

·	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		14.4		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		4.66		nF
C_{rss}	Reverse Transfer Capacitance	f=1MHz		0.29		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		280		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 100V$		106		пC
Q_{gd}	Gate – Drain Charge	$I_D = 208A$		134		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		32		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$ $V_{Bus} = 133V$ $I_D = 208A$		64		ns
$T_{d(off)}$	Turn-off Delay Time			88		
T_{f}	Fall Time	$R_G = 2.5\Omega$		116		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$, $V_{Bus} = 133V$ $I_D = 208A$, $R_G = 2.5\Omega$		1698		1
E_{off}	Turn-off Switching Energy			1858		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		1872		
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 133V$ $I_D = 208A, R_G = 2.5\Omega$		1972		μJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
I_S	Continuous Source current		$Tc = 25^{\circ}C$			208	A	
1 _S	(Body diode)		$Tc = 80^{\circ}C$			155	A	
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -208A$				1.3	V	
dv/dt	Peak Diode Recovery •					5	V/ns	
t _{rr}	Reverse Recovery Time		$T_j = 25$ °C			230	- ns	
·rr	reverse receivery Time	$I_S = -208A$ $V_R = 133V$	$T_j = 125$ °C			450		
Q _{rr}	Reverse Recovery Charge	$di_{S}/dt = 200A/\mu s$	$T_j = 25^{\circ}C$		1.8		μC	
			$T_{j} = 125^{\circ}C$		6.8		۳۵	

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

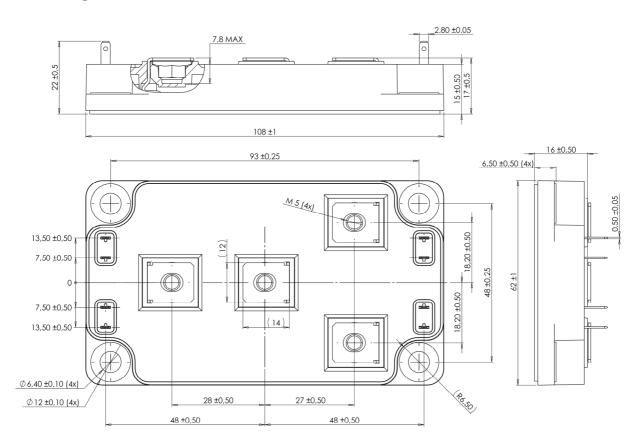
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Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance					0.16	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature					100	
Torque	Mounting forque	To heatsink	M6	3		5	N.m
Torque		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

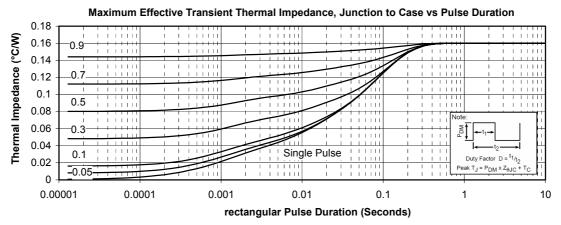
SP6 Package outline (dimensions in mm)

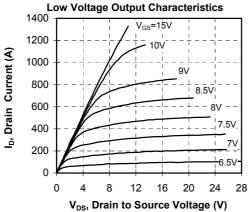


See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com



Typical Performance Curve





R_{DS(on)} Drain to Source ON Resistance

1.2

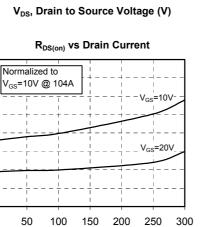
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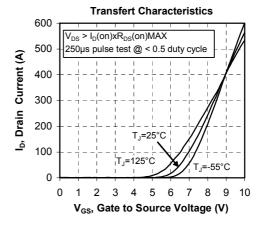
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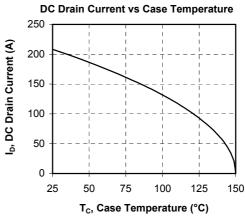
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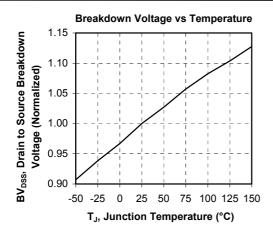


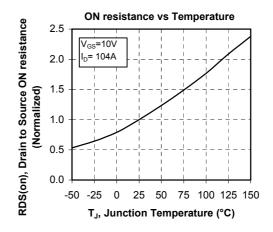
I_D, Drain Current (A)

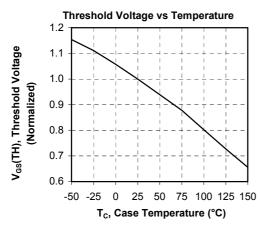


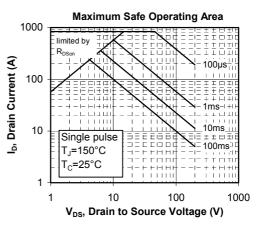


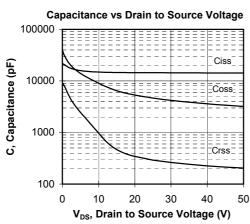


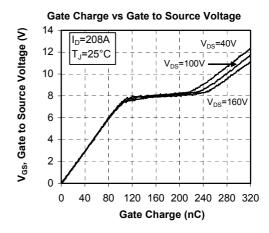




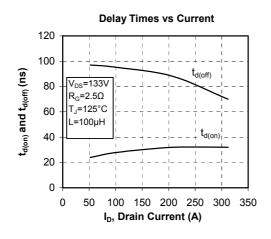


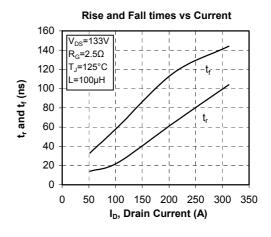


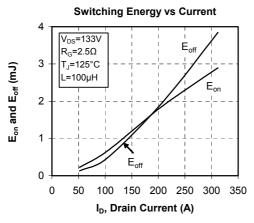


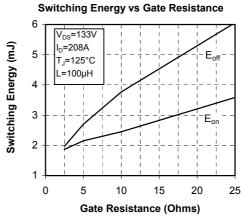


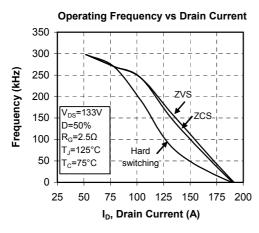


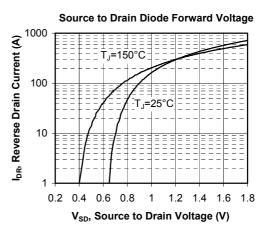














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